

MiniSKiiP[®] 2

3-phase bridge rectifier + brake chopper

SKiiP 28ANB16V10

Target Data

Features

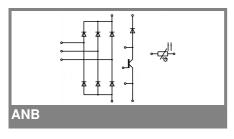
- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

Input bridge for Inverter up to 39 kVA

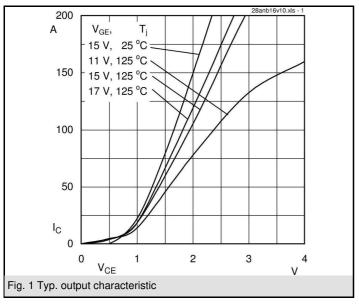
Remarks

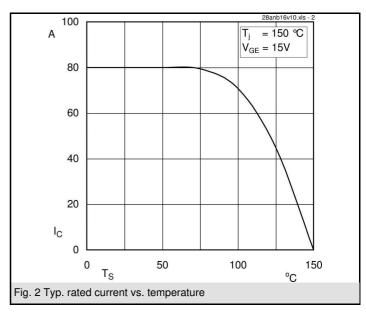
• V_{CEsat} , V_F = chip level value

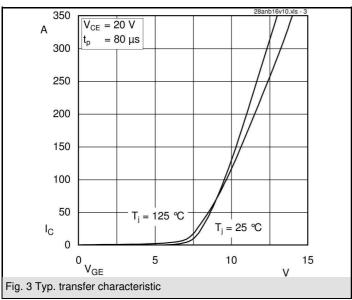


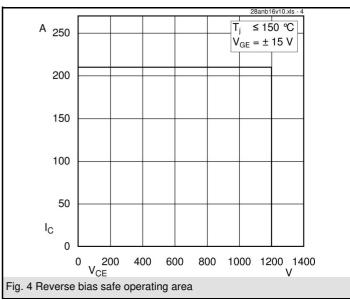
| Absolute Maximum Ratings T _s = 25 °C, unless otherwise specified | | | | | | | |
|---|---|-------------------|-------|--|--|--|--|
| Symbol | Conditions | Values | Units | | | | |
| IGBT - Chopper | | | | | | | |
| V_{CES} | | 1200 | V | | | | |
| I _C | T _s = 25 (70) °C | 118 (88) | Α | | | | |
| I _{CRM} | | 210 | Α | | | | |
| V_{GES} | | ± 20 | V | | | | |
| T _j | | - 40 + 150 | °C | | | | |
| Diode - Chopper | | | | | | | |
| I _F | T _s = 25 (70) °C | 118 (88) | Α | | | | |
| I _{FRM} | | 210 | Α | | | | |
| T _j | | - 40 + 150 | °C | | | | |
| Diode - Rectifier | | | | | | | |
| V_{RRM} | | 1600 | V | | | | |
| I _F | T _s = 70 °C | 83 | Α | | | | |
| I _{FSM} | $t_p = 10 \text{ ms, sin } 180 ^\circ, T_i = 25 ^\circ\text{C}$ | 1000 | Α | | | | |
| i²t | $t_{\rm p}^{\rm r}$ = 10 ms, sin 180 °, $T_{\rm i}$ = 25 °C | 6600 | A²s | | | | |
| T _j | | - 40 + 150 | °C | | | | |
| Module | | | | | | | |
| I _{tRMS} | per power terminal (20 A / spring) | 80 | Α | | | | |
| T _{stg} | | - 40 + 125 | °C | | | | |
| V _{isol} | AC, 1 min. | 2500 | V | | | | |

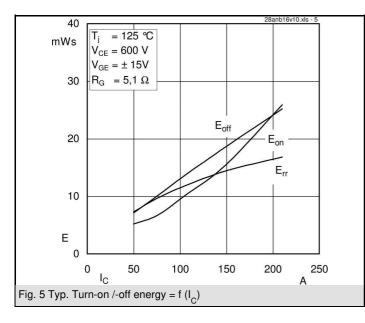
| Characteristics | | T _s = 25 °C, unless otherwise specified | | | | | | |
|--|--|--|--|---|--------------------------------|--|--|--|
| Symbol | Conditions | min. | typ. | max. | Units | | | |
| IGBT - Chopper | | | | | | | | |
| V _{CEsat} V _{GE(th)} V _{CE(TO)} r _T C _{ies} | $I_{Cnom} = 105 \text{ A}, T_j = 25 (125) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_C = 3 \text{ mA}$ $T_j = 25 (125) ^{\circ}\text{C}$ $T_j = 25 (125) ^{\circ}\text{C}$ $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ | 5 | 1,7 (2) 5,8 1 (0,9) 6,7 (10) 8,4 | 2,1 (2,4) 6,5 1,2 (1,1) 8,6 (12) | V V V mΩ nF | | | |
| C _{oes} C _{res} R _{th(j-s)} | $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ per IGBT | | 1,5 1,1 0,4 | | nF nF K/W | | | |
| $\begin{aligned} & t_{d(on)} \\ & t_r \\ & t_{d(off)} \\ & t_f \\ & E_{on} \\ & E_{off} \end{aligned}$ | under following conditions $\begin{split} &V_{CC}=600 \text{ V}, V_{GE}=\pm 15 \text{ V} \\ &I_{Cnom}=105 \text{ A}, T_j=125 ^{\circ}\text{C} \\ &R_{Gon}=R_{Goff}=5,1 \Omega \\ &\text{inductive load} \end{split}$ | | 65 30 465 95 10,1 13,6 | | ns ns ns ns mJ | | | |
| Diode - Chopper | | | | | | | | |
| $V_{F} = V_{EC}$ $V_{(TO)}$ r_{T} $R_{th(j-s)}$ I_{RRM} Q_{rr} | I_{Fnom} = 105 A, T_j = 25 (125) °C T_j = 25 (125) °C T_j = 25 (125) °C per diode under following conditions I_{Fnom} = 105 A, V_R = 600 V | | 1,6 (1,6) 1 (0,8) 5,7 (7,6) 0,55 180 26 | 1,8 (1,8) 1,1 (0,9) 6,7 (8,6) | V V mΩ K/W A μC | | | |
| E _{rr} | V _{GE} = 0 V, T _j = 125 °C di _F /dt = 4350 A/μs | | 11,8 | | mJ | | | |
| Diode - Re V_F $V_{(TO)}$ r_T $R_{th(j-s)}$ | ectifier $I_{Fnom} = 75 \text{ A, T}_{j} = 25 \text{ °C}$ $T_{j} = 150 \text{ °C}$ $T_{j} = 150 \text{ °C}$ per diode | | 1,2 0,8 7 0,7 | | V V mΩ K/W | | | |
| Temperature Sensor | | | | | | | | |
| R _{ts} | 3 %, T _r = 25 (100) °C | | 1000(1670) | | Ω | | | |
| Mechanic w | al Data | | 65 | | g | | | |
| M_s | Mounting torque | 2 | | 2,5 | Nm | | | |

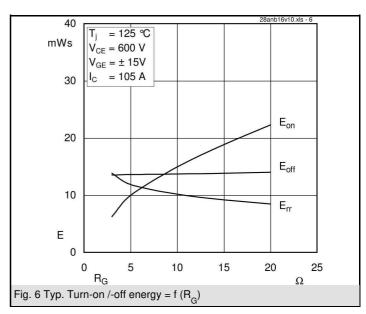


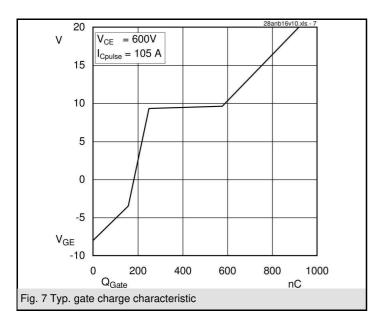


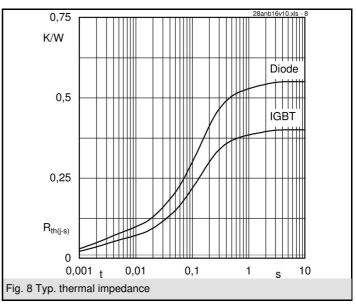


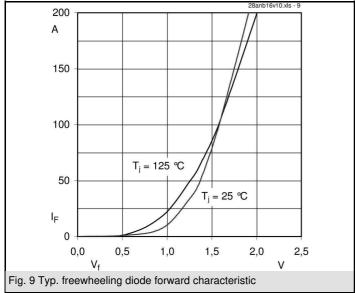


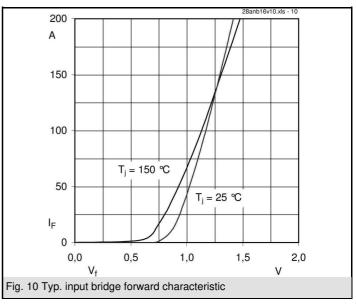


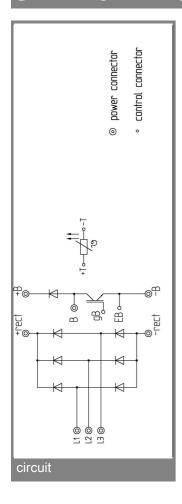


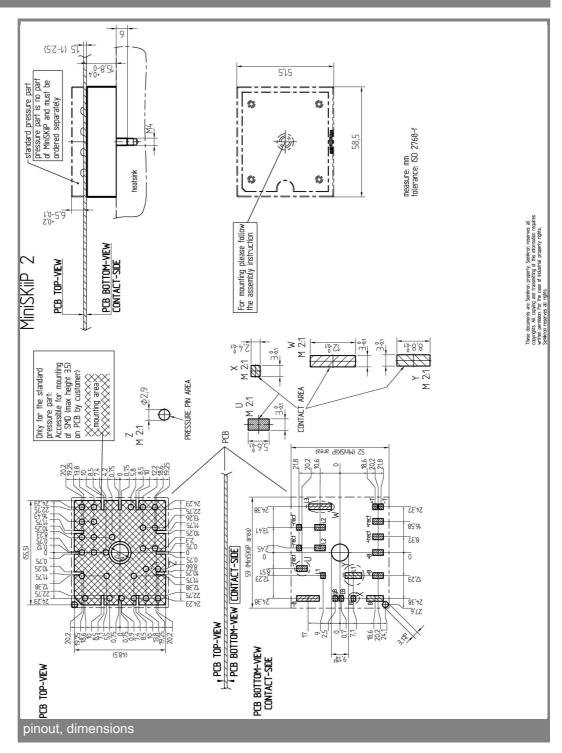












This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

^{*} The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.